













TMUX1247

JAJSHS9-AUGUST 2019

TMUX1247 5V 双方向、2:1 (SPDT) の汎用スイッチ

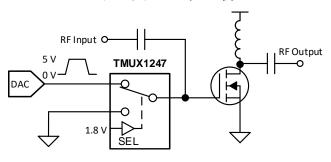
1 特長

- レール・ツー・レールの動作
- 双方向の信号パス
- 1.8V ロジック互換
- フェイルセーフ・ロジック
- 低いオン抵抗: 3Ω
- 広い電源電圧範囲: 1.08V~5.5V
- -40°C~+125°C の動作温度範囲
- 低い消費電流: 4nA
- 遷移時間: 14ns
- Break-Before-Make のスイッチング動作
- ESD 保護 (HBM): 2000V

2 アプリケーション

- アナログおよびデジタル・スイッチング
- I2C および SPI バスの多重化
- リモート無線ユニット
- アクティブ・アンテナ・システム (AAS) の mMIMO
- バーコード・スキャナ
- モータ・ドライブ
- ビルディング・オートメーション
- アナログ入力モジュール
- パワー・デリバリ
- ビデオ監視
- POS システム
- 家電製品
- コンシューマ・オーディオ

アプリケーションの例



3 概要

TMUX1247 は、汎用の CMOS (相補型金属酸化膜半導体) 単極双投 (SPDT) スイッチです。TMUX1247 は、SEL ピンの状態に基づいて、2 つのソース入力間のスイッチングを行います。 $1.08V\sim5.5V$ の広い動作電源電圧範囲により、個人用電子機器からビルディング・オートメーションまで、幅広い用途に使用可能です。このデバイスは、ソース (Sx) およびドレイン (D) ピンで、GND から V_{DD} までの範囲の双方向アナログおよびデジタル信号をサポートします。消費電流が $4\mu A$ と低いため、携帯型アプリケーションで使用できます。

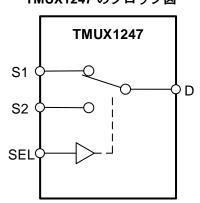
すべてのロジック入力には1.8Vロジック互換のスレッショルドがあり、有効な電源電圧範囲で動作していれば、TTLとCMOSの両方のロジックと互換性が保証されます。フェイルセーフ・ロジック回路により、電源ピンよりも前に制御ピンに電圧が印加されるため、デバイスへの損傷の可能性が避けられます。

製品情報⁽¹⁾

型番	パッケージ	本体サイズ(公称)
TMUX1247	SC70 (6)	2.00mm×1.25mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にあるパッケージ・オプションについての付録を参照してください。

TMUX1247 のブロック図







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4 改訂履歴

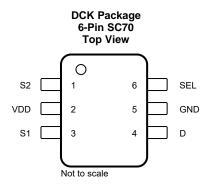
資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

日付	リビジョン	注
2019 年 8 月	*	初版



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5 Pin Configuration and Functions



Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.	ITPE\"	DESCRIPTION
S2	1	I/O	Source pin 2. Can be an input or output.
V _{DD}	2	Р	Positive power supply. This pin is the most positive power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1 μ F to 10 μ F between V _{DD} and GND.
S1	3	I/O	Source pin 1. Can be an input or output.
D	4	I/O	Drain pin. Can be an input or output.
GND	5	Р	Ground (0 V) reference
SEL	6	I	Select pin: controls state of the switch according to 表 1. (Logic Low = S1 to D, Logic High = S2 to D)

⁽¹⁾ I = input, O = output, I/O = input and output, P = power

TEXAS INSTRUMENTS

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)(2)(3)

		MIN	MAX	UNIT
V_{DD}	Supply voltage	-0.5	6	V
V _{SEL} or V _{EN}	Logic control input pin voltage (SEL)	-0.5	6	V
I _{SEL} or I _{EN}	Logic control input pin current (SEL)	-30	30	mA
V _S or V _D	Source or drain voltage (Sx, D)	-0.5	V _{DD} +0.5	V
I _S or I _{D (CONT)}	Source or drain continuous current (Sx, D)	-50	50	mA
I _K	Diode clamp current ⁽⁴⁾	-30	30	mA
T _{stg}	Storage temperature	-65	150	°C
T_{J}	Junction temperature		150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(3) All voltages are with respect to ground, unless otherwise specified.

6.2 ESD Ratings

			VALUE	UNIT
V	Flootroctatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	V
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	±750	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

0.0. op 0.0	amig need an temperature range (amoes earer mee need)			
		MIN	NOM MAX	UNIT
V_{DD}	Supply voltage	1.08	5.5	V
V_S or V_D	Signal path input/output voltage (source or drain pin) (Sx, D)	0	V_{DD}	V
V_{SEL}	Logic control input pin voltage (SEL)	0	5.5	V
T _A	Ambient temperature	-40	125	°C

6.4 Thermal Information

		TMUX1247	
	THERMAL METRIC ⁽¹⁾	DCK (SC70)	UNIT
		6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	243.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	180.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	106.3	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	89.1	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	106.0	°C/W
R ₀ JC(bot)	Junction-to-case (bottom) thermal resistance	N/A	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

⁴⁾ Pins are diode-clamped to the power-supply rails. Over voltage signals must be voltage and current limited to maximum ratings.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

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6.5 Electrical Characteristics (V_{DD} = 5 V ±10 %), GND = 0 V unless otherwise specified.

at $T_A = 25$ °C, $V_{DD} = 5$ V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
ANALO	G SWITCH						
		$V_S = 0 \text{ V to } V_{DD}$	25°C		3		Ω
R _{ON}	On-resistance	I _{SD} = 10 mA	-40°C to +85°C			5	Ω
		Refer to On-Resistance	-40°C to +125°C			6	Ω
		$V_S = 0 \text{ V to } V_{DD}$	25°C		0.15		Ω
ΔR_{ON}	On-resistance matching between channels	$I_{SD} = 10 \text{ mA}$	-40°C to +85°C			1	Ω
	ona mois	Refer to On-Resistance	-40°C to +125°C			1	Ω
		$V_S = 0 \text{ V to } V_{DD}$	25°C		1.5		Ω
R _{ON}	On-resistance flatness	I _{SD} = 10 mA	-40°C to +85°C		2		Ω
FLAT		Refer to On-Resistance	-40°C to +125°C		3		Ω
		V _{DD} = 5 V	25°C		±75		nA
	Source off leakage current ⁽¹⁾	Switch Off $V_D = 4.5 \text{ V} / 1.5 \text{ V}$ $V_S = 1.5 \text{ V} / 4.5 \text{ V}$ Refer to Off-Leakage Current	-40°C to +85°C	-150		150	nA
I _{S(OFF)}			-40°C to +125°C	-175		175	nA
	Channel on leakage current	v _{DD} = 5 V Switch On $V_D = V_S = 4.5 \text{ V} / 1 \text{ V}$ Refer to On-Leakage Current	25°C		±200		nA
$I_{D(ON)}$			-40°C to +85°C	-500		500	nA
I _{S(ON)}			-40°C to +125°C	-750		750	nA
LOGIC	INPUTS						•
V_{IH}	Input logic high		-40°C to 125°C	1.42		5.5	V
V_{IL}	Input logic low		-40°C to 125°C	0		0.87	V
I _{IH} I _{IL}	Input leakage current		25°C		±0.005		μΑ
I _{IH} I _{IL}	Input leakage current		-40°C to +125°C			±0.05	μΑ
C _{IN}	Digital input capacitance		25°C		1		pF
C _{IN}	Digital input capacitance		-40°C to +125°C			2	pF
POWER	RSUPPLY						
	V supply supply	Digital lagrata 0 V as 5 5 V	25°C		0.007		μA
I _{DD}	V _{DD} supply current	Digital Inputs = 0 V or 5.5 V	-40°C to +125°C			1.5	μA

⁽¹⁾ When V_S is 4.5 V, V_D is 1.5 V or when V_S is 1.5 V, V_D is 4.5 V.



Electrical Characteristics (V_{DD} = 5 V ±10 %), GND = 0 V unless otherwise specified. (continued)

at $T_A = 25$ °C, $V_{DD} = 5$ V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
DYNAN	IIC CHARACTERISTICS						
		., .,	25°C		12		ns
t_{TRAN}	Switching time between channels	$V_S = 3 V$ $R_L = 200 \Omega, C_L = 15 pF$	-40°C to +85°C			18	ns
		π_ = 200 Ω, Θ_ = 13 μ	-40°C to +125°C			19	ns
		., .,	25°C		8		ns
tOPEN	Break before make time	$V_S = 3 V$ $R_L = 200 \Omega, C_L = 15 pF$	-40°C to +85°C	1			ns
(BBM)		Ν_ = 200 Ω, Ο_ = 13 μ	-40°C to +125°C	1			ns
Q _C	Charge Injection	$V_S = V_{DD}/2$ $R_S = 0 \Omega$, $C_L = 1 nF$	25°C		-10		рС
_		$R_L = 50 \Omega$, $C_L = 5 pF$ f = 1 MHz	25°C		-65		dB
O _{ISO}	Off Isolation	$R_L = 50 \Omega, C_L = 5 pF$ f = 10 MHz	25°C		–45		dB
	0 1 1	$R_L = 50 \Omega$, $C_L = 5 pF$ f = 1 MHz	25°C		-65		dB
X _{TALK}	Crosstalk	$R_L = 50 \Omega, C_L = 5 pF$ f = 10 MHz	25°C		-45		dB
BW	Bandwidth	$R_L = 50 \Omega$, $C_L = 5 pF$	25°C		250		MHz
C _{SOFF}	Source off capacitance	f = 1 MHz	25°C		7		pF
C _{SON} C _{DON}	On capacitance	f = 1 MHz	25°C		23		pF



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6.6 Electrical Characteristics (V_{DD} = 3.3 V ±10 %), GND = 0 V unless otherwise specified.

at $T_A = 25$ °C. $V_{DD} = 3.3$ V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
ANALO	G SWITCH						-
		$V_S = 0 \text{ V to } V_{DD}$	25°C		4.5		Ω
R _{ON}	On-resistance	I _{SD} = 10 mA	-40°C to +85°C			12.5	Ω
		Refer to On-Resistance	-40°C to +125°C			13	Ω
		$V_S = 0 \text{ V to } V_{DD}$	25°C		0.15		Ω
ΔR_{ON}	On-resistance matching between channels	$I_{SD} = 10 \text{ mA}$	-40°C to +85°C			1	Ω
	CHAIIIGIS	Refer to On-Resistance	-40°C to +125°C			1	Ω
		$V_S = 0 \text{ V to } V_{DD}$	25°C		3.5		Ω
R _{ON}	On-resistance flatness	I _{SD} = 10 mA	-40°C to +85°C		4		Ω
FLAT		Refer to On-Resistance	-40°C to +125°C		5		Ω
		V _{DD} = 3.3 V	25°C		±75		nA
	Source off leakage current ⁽¹⁾	Switch Off $V_D = 3 \text{ V / 1 V}$ $V_S = 1 \text{ V / 3 V}$ Refer to Off-Leakage Current	-40°C to +85°C	-150		150	nA
I _{S(OFF)}			-40°C to +125°C	-175		175	nA
	Channel on leakage current	V _{DD} = 3.3 V Switch On	25°C		±200		nA
$I_{D(ON)}$			-40°C to +85°C	-500		500	nA
I _{S(ON)}			-40°C to +125°C	-750		750	nA
LOGIC	INPUTS						•
V_{IH}	Input logic high		-40°C to 125°C	1.35		5.5	V
V_{IL}	Input logic low		-40°C to 125°C	0		8.0	V
I _{IH} I _{IL}	Input leakage current		25°C	:	±0.005		μΑ
I _{IH} I _{IL}	Input leakage current		-40°C to +125°C			±0.05	μΑ
C _{IN}	Logic input capacitance		25°C		1		pF
C _{IN}	Logic input capacitance		-40°C to +125°C			2	pF
POWER	RSUPPLY						
	V supply supply	Digital lagrata 0 V as 5 5 V	25°C		0.004		μA
I_{DD}	V _{DD} supply current	Digital Inputs = 0 V or 5.5 V	-40°C to +125°C			0.8	μA

⁽¹⁾ When V_S is 3 V, V_D is 1 V or when V_S is 1 V, V_D is 3 V.



Electrical Characteristics (V_{DD} = 3.3 V ±10 %), GND = 0 V unless otherwise specified. (continued)

at $T_A = 25$ °C, $V_{DD} = 3.3$ V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
DYNAN	IIC CHARACTERISTICS		1			'	
			25°C		14		ns
t _{TRAN}	Switching time between channels	$V_S = 2 V$ $R_L = 200 \Omega, C_L = 15 pF$	-40°C to +85°C			20	ns
		π_ = 200 Ω, Ο[= 10 μι	-40°C to +125°C			22	ns
		V 0 V	25°C		8		ns
t _{OPEN} (BBM)	Break before make time	$V_S = 2 V$ $R_L = 200 \Omega, C_L = 15 pF$	-40°C to +85°C	1			ns
(BBIVI)		11 <u>1</u> = 200 <u>12</u> , <u>0</u> [= 10 pi	-40°C to +125°C	1			ns
$Q_{\mathbb{C}}$	Charge Injection	$V_S = V_{DD}/2$ $R_S = 0 \Omega, C_L = 1 nF$	25°C		-6		рС
0	Off Isolation	$R_L = 50 \Omega$, $C_L = 5 pF$ f = 1 MHz Refer to Off Isolation	25°C		-65		dB
O _{ISO}		$R_L = 50 \Omega$, $C_L = 5 pF$ f = 10 MHz Refer to Off Isolation	25°C		-45		dB
V	Crosstalk	$R_L = 50 \ \Omega, \ C_L = 5 \ pF$ $f = 1 \ MHz$ Refer to Crosstalk	25°C		-65		dB
X _{TALK}		$R_L = 50 \Omega$, $C_L = 5 pF$ f = 10 MHz Refer to Crosstalk	25°C		-45		dB
BW	Bandwidth	$R_L = 50 \Omega$, $C_L = 5 pF$ Refer to Bandwidth	25°C		250	_	MHz
C _{SOFF}	Source off capacitance	f = 1 MHz	25°C	-	7		pF
C _{SON} C _{DON}	On capacitance	f = 1 MHz	25°C		23		pF

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6.7 Electrical Characteristics (V_{DD} = 1.8 V ±10 %), GND = 0 V unless otherwise specified.

at $T_A = 25$ °C, $V_{DD} = 1.8 \text{ V}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
ANALO	G SWITCH						
		$V_S = 0 \text{ V to } V_{DD}$	25°C		40		Ω
R_{ON}	On-resistance	I _{SD} = 10 mA	-40°C to +85°C			80	Ω
		Refer to On-Resistance	-40°C to +125°C			80	Ω
		$V_S = 0 \text{ V to } V_{DD}$	25°C		0.4		Ω
ΔR_{ON}	On-resistance matching between channels	$I_{SD} = 10 \text{ mA}$	-40°C to +85°C			1.5	Ω
	Chariners	Refer to On-Resistance	-40°C to +125°C			1.5	Ω
		V _{DD} = 1.98 V	25°C		±75		nA
	(1)	Switch Off	-40°C to +85°C	-150		150	nA
I _{S(OFF)}	Source off leakage current ⁽¹⁾	$V_D = 1.8 \text{ V} / 1 \text{ V}$ $V_S = 1 \text{ V} / 1.8 \text{ V}$ Refer to Off-Leakage Current	-40°C to +125°C	-175		175	nA
	Channel on leakage current	V _{DD} = 1.98 V	25°C		±200		nA
$I_{D(ON)}$		Switch On	-40°C to +85°C	-500		500	nA
I _{S(ON)}		$V_D = V_S = 1.62 \text{ V} / 1 \text{ V}$	-40°C to +125°C	-750		750	nA
DIGITA	L INPUTS						
V _{IH}	Input logic high		-40°C to +125°C	1.07		5.5	V
V _{IL}	Input logic low		-40°C to +125°C	0		0.68	V
I _{IH} I _{IL}	Input leakage current		25°C		±0.005		μA
I _{IH} I _{IL}	Input leakage current		-40°C to +125°C			±0.05	μΑ
C _{IN}	Logic input capacitance		25°C		1		pF
C _{IN}	Logic input capacitance		-40°C to +125°C			2	pF
POWER	RSUPPLY						
	V supply supply	Lania lanuta OV as 5.5V	25°C		0.002		μA
I _{DD}	V _{DD} supply current	Logic Inputs = 0 V or 5.5 V	-40°C to +125°C			0.52	μA

⁽¹⁾ When V_S is 1.8 V, V_D is 1 V or when V_S is 1 V, V_D is 1.8 V.

TEXAS INSTRUMENTS

Electrical Characteristics (V_{DD} = 1.8 V ±10 %), GND = 0 V unless otherwise specified. (continued)

at $T_A = 25$ °C, $V_{DD} = 1.8$ V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
LOGIC	INPUTS		,				
			25°C		24		ns
t _{TRAN}	Switching time between channels	$V_S = 1 V$ $R_L = 200 \Omega, C_L = 15 pF$	-40°C to +85°C			44	ns
		κ[= 200 Ω, Ο[= 15 μ	-40°C to +125°C			45	ns
			25°C		16		ns
tOPEN	Break before make time	$V_S = 1 V$ $R_1 = 200 \Omega, C_1 = 15 pF$	-40°C to +85°C	1			ns
(BBM)		Ν_ = 200 Ω, Ο[= 13 μι	-40°C to +125°C	1			ns
Q_{C}	Charge Injection	$V_S = V_{DD}/2$ $R_S = 0 \Omega$, $C_L = 1 nF$	25°C		-3		рС
	Off Isolation	$R_L = 50 \Omega$, $C_L = 5 pF$ f = 1 MHz Refer to Off Isolation	25°C		-65		dB
O _{ISO}		$R_L = 50 \Omega$, $C_L = 5 pF$ f = 10 MHz Refer to Off Isolation	25°C		–4 5		dB
V	Connectelle	$R_L = 50 \ \Omega, \ C_L = 5 \ pF$ $f = 1 \ MHz$ Refer to Crosstalk	25°C		-65		dB
X _{TALK}	Crosstalk	$R_L = 50 \Omega$, $C_L = 5 pF$ f = 10 MHz Refer to Crosstalk	25°C		–4 5		dB
BW	Bandwidth	$R_L = 50 \Omega, C_L = 5 pF$	25°C		250		MHz
C _{SOFF}	Source off capacitance	f = 1 MHz	25°C		7		pF
C _{SON} C _{DON}	On capacitance	f = 1 MHz	25°C		23		pF

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6.8 Electrical Characteristics (V_{DD} = 1.2 V ±10 %), GND = 0 V unless otherwise specified.

at $T_A = 25$ °C. $V_{DD} = 1.2$ V (unless otherwise noted)

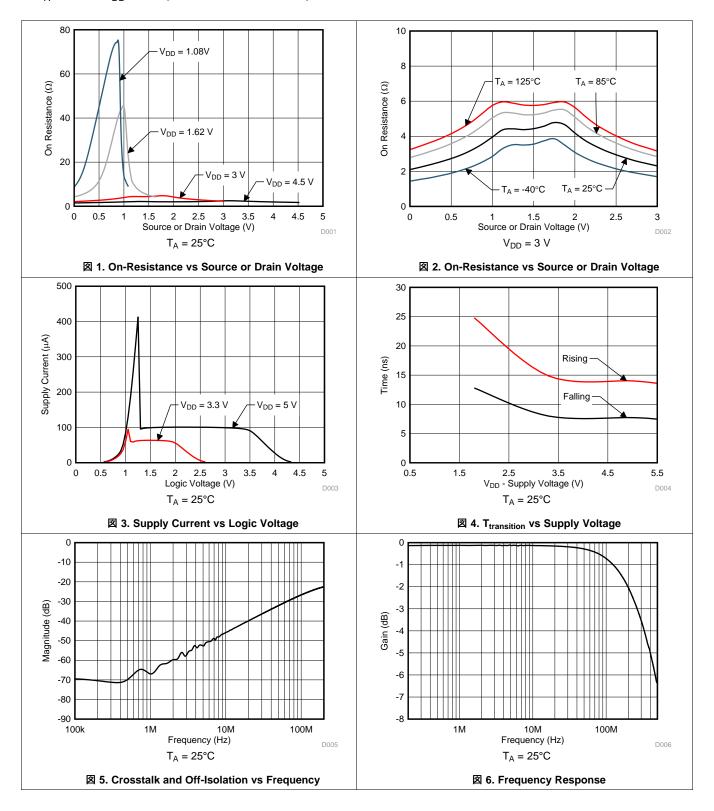
	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
ANALO	G SWITCH		'				
			25°C		70		Ω
R _{ON}	On-resistance	$V_S = 0 \text{ V to } V_{DD}$ $I_{DS} = 10 \text{ mA}$	-40°C to +85°C			105	Ω
		IDS = TO THA	-40°C to +125°C			105	Ω
		.,	25°C		0.4		Ω
ΔR_{ON}	On-resistance matching between channels	$V_S = 0 \text{ V to } V_{DD}$ $I_{DS} = 10 \text{ mA}$	-40°C to +85°C			1.5	Ω
	0.14.11.0.0	102 - 10 1101	-40°C to +125°C			1.5	Ω
		$V_{DD} = 1.32 \text{ V}$	25°C		±75		nA
I _{S(OFF)}	Source off leakage current ⁽¹⁾	Switch Off V _D = 1.2 V / 1 V	-40°C to +85°C	-150		150	nA
, ,		$V_S = 1 \text{ V} / 1.2 \text{ V}$	-40°C to +125°C	-175		175	nA
		V _{DD} = 1.32 V	25°C		±200		nA
I _{D(ON)}	Channel on leakage current	Switch On	-40°C to +85°C	-500		500	nA
I _{S(ON)}		$V_D = V_S = 1 \text{ V} / 0.8 \text{ V}$	-40°C to +125°C	-750		750	nA
DIGITA	L INPUTS						
V_{IH}	Input logic high		-40°C to +125°C	0.96			V
V_{IL}	Input logic low		-40°C to +125°C			0.36	V
I _{IH} I _{IL}	Input leakage current		25°C		±0.005		μΑ
I _{IH} I _{IL}	Input leakage current		-40°C to +125°C			±0.10	μΑ
C _{IN}	Digital input capacitance		25°C		1		pF
C _{IN}	Digital input capacitance		-40°C to +125°C			2	рF
POWER	SUPPLY		•				
	V gunnly gurrent	Digital Inputs = 0 V or 5.5 V	25°C		0.0015		μΑ
I _{DD}	V _{DD} supply current	Digital inputs = 0 v of 5.5 v	-40°C to +125°C			0.45	μΑ
DYNAN	IIC CHARACTERISTICS	.					
		$V_{IN} = V_{DD}$	25°C		40		ns
t _{TRAN}	Switching time between channels	V _S = 1 V	-40°C to +85°C			175	ns
		$R_L = 200 \Omega, C_L = 15 pF$	-40°C to +125°C			175	ns
+		V _S = 1 V	25°C		27		ns
topen (BBM)	Break before make time	$R_L = 200 \Omega, C_L = 15 pF$	-40°C to +85°C	1			ns
			-40°C to +125°C	1			ns
Q _C	Charge Injection	$V_S = (V_{DD} + V_{SS})/2$ $R_S = 0 \Omega, C_L = 1 \text{ nF}$	25°C		±5		рC
0	Off Isolation	$R_L = 50 \Omega$, $C_L = 5 pF$ f = 1 MHz	25°C		-64		dB
O _{ISO}	On isolation	$R_L = 50 \Omega$, $C_L = 5 pF$ f = 10 MHz	25°C		-44		dB
	0	$R_L = 50 \Omega$, $C_L = 5 pF$ f = 1 MHz	25°C		-64		dB
X _{TALK}	Crosstalk	$R_L = 50 \Omega, C_L = 5 pF$ f = 10 MHz	25°C		-44		dB
BW	Bandwidth	$R_L = 50 \Omega, C_L = 5 pF$	25°C		250		MHz
C _{SOFF}	Source off capacitance	f = 1 MHz	25°C		7		pF
C _{SON} C _{DON}	On capacitance	f = 1 MHz	25°C		23		pF

⁽¹⁾ When V_S is 1 V, V_D is 1.2 V or when V_S is 1.2 V, V_D is 1 V.

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6.9 Typical Characteristics

at $T_A = 25$ °C, $V_{DD} = 5$ V (unless otherwise noted)





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7 Parameter Measurement Information

7.1 On-Resistance

The on-resistance of a device is the ohmic resistance between the source (Sx) and drain (D) pins of the device. The on-resistance varies with input voltage and supply voltage. The symbol R_{ON} is used to denote on-resistance. The measurement setup used to measure R_{ON} is shown in 2 7. Voltage (V) and current (I_{SD}) are measured using this setup, and R_{ON} is computed with $R_{ON} = V / I_{SD}$:

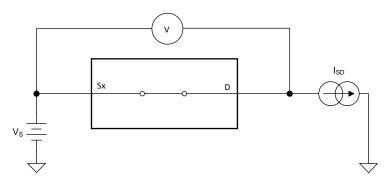


図 7. On-Resistance Measurement Setup

7.2 Off-Leakage Current

Source leakage current is defined as the leakage current flowing into or out of the source pin when the switch is off. This current is denoted by the symbol $I_{S(OFF)}$.

The setup used to measure off-leakage current is shown in ≥ 8.

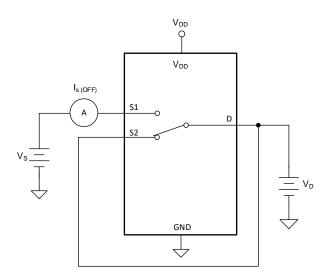


図 8. Off-Leakage Measurement Setup

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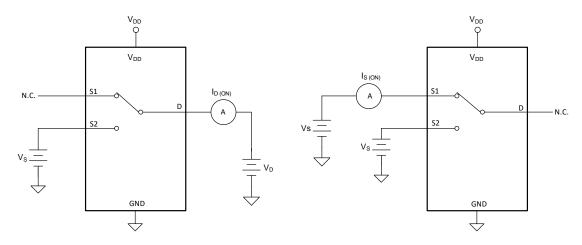
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7.3 On-Leakage Current

Source on-leakage current is defined as the leakage current flowing into or out of the source pin when the switch is on. This current is denoted by the symbol $I_{S(ON)}$.

Drain on-leakage current is defined as the leakage current flowing into or out of the drain pin when the switch is on. This current is denoted by the symbol $I_{D(ON)}$.

Either the source pin or drain pin is left floating during the measurement. \boxtimes 9 shows the circuit used for measuring the on-leakage current, denoted by $I_{S(ON)}$ or $I_{D(ON)}$.



☑ 9. On-Leakage Measurement Setup

7.4 Transition Time

Transition time is defined as the time taken by the output of the device to rise or fall 10% after the logic control signal has risen or fallen past the logic threshold. The 10% transition measurement is utilized to provide the timing of the device. System level timing can then account for the time constant added from the load resistance and load capacitance.

10 shows the setup used to measure transition time, denoted by the symbol t_{TRANSITION}.

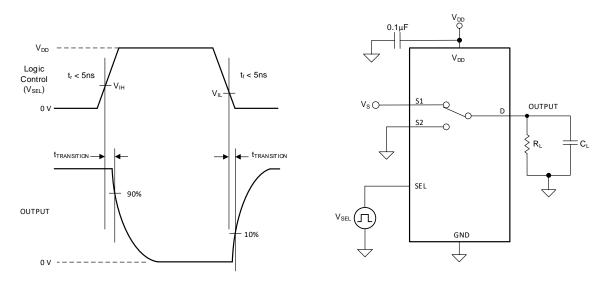


図 10. Transition-Time Measurement Setup



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7.5 Break-Before-Make

Break-before-make delay is a safety feature that prevents two inputs from connecting when the device is switching. The output first breaks from the on-state switch before making the connection with the next on-state switch. The time delay between the *break* and the *make* is known as break-before-make delay. 🗵 11 shows the setup used to measure break-before-make delay, denoted by the symbol topen(BBM).

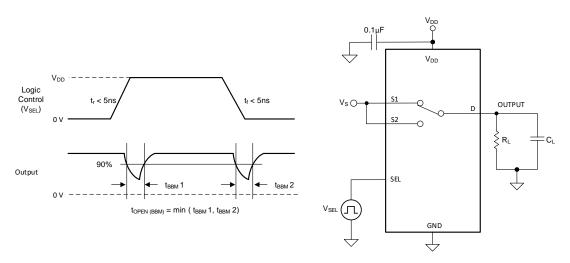


図 11. Break-Before-Make Delay Measurement Setup

7.6 Charge Injection

The TMUX1247 has a transmission-gate topology. Any mismatch in capacitance between the NMOS and PMOS transistors results in a charge injected into the drain or source during the falling or rising edge of the gate signal. The amount of charge injected into the source or drain of the device is known as charge injection, and is denoted by the symbol Q_C . $\boxed{2}$ 12 shows the setup used to measure charge injection from Drain (D) to Source (Sx).

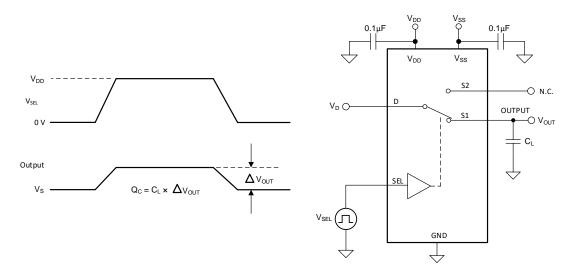


図 12. Charge-Injection Measurement Setup

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7.7 Off Isolation

Off isolation is defined as the ratio of the signal at the drain pin (D) of the device when a signal is applied to the source pin (Sx) of an off-channel. 🗵 13 shows the setup used to measure, and the equation used to calculate off isolation.

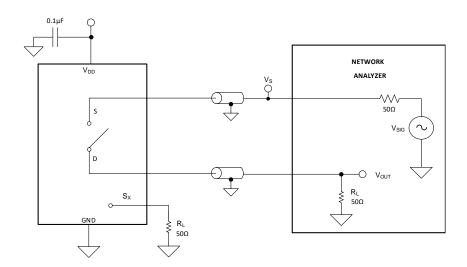


図 13. Off Isolation Measurement Setup

Off Isolation =
$$20 \cdot \text{Log}\left(\frac{V_{\text{OUT}}}{V_{\text{S}}}\right)$$
 (1)

7.8 Crosstalk

Crosstalk is defined as the ratio of the signal at the drain pin (D) of a different channel, when a signal is applied at the source pin (Sx) of an on-channel. 🗵 14 shows the setup used to measure, and the equation used to calculate crosstalk.

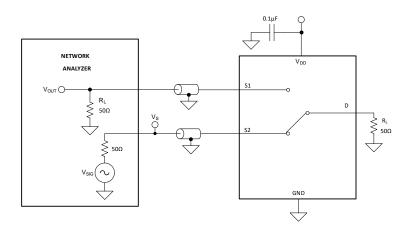


図 14. Crosstalk Measurement Setup

Channel-to-Channel Crosstalk =
$$20 \cdot \text{Log} \left(\frac{V_{\text{OUT}}}{V_{\text{S}}} \right)$$
 (2)



7.9 Bandwidth

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Bandwidth is defined as the range of frequencies that are attenuated by less than 3 dB when the input is applied to the source pin (Sx) of an on-channel, and the output is measured at the drain pin (D) of the device. \boxtimes 15 shows the setup used to measure bandwidth.

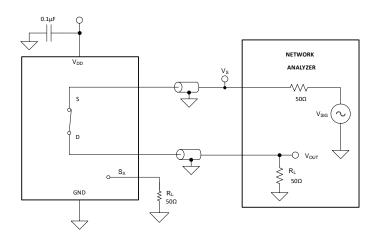


図 15. Bandwidth Measurement Setup

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8 Detailed Description

8.1 Overview

The TMUX1247 is an 2:1 (SPDT), 1-channel switch where the input is controlled with a single select (SEL) control pin.

8.2 Functional Block Diagram

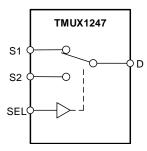


図 16. TMUX1247 Functional Block Diagram

8.3 Feature Description

8.3.1 Bidirectional Operation

The TMUX1247 conducts equally well from source (Sx) to drain (D) or from drain (D) to source (Sx). The device has very similar characteristics in both directions and supports both analog and digital signals.

8.3.2 Rail to Rail Operation

The valid signal path input/output voltage for TMUX1247 ranges from GND to V_{DD}.

8.3.3 1.8 V Logic Compatible Inputs

The TMUX1247 has 1.8-V logic compatible control for the logic control input (SEL). The logic input threshold scales with supply but still provides 1.8-V logic control when operating at 5.5 V supply voltage. 1.8-V logic level inputs allow the TMUX1247 to interface with processors that have lower logic I/O rails and eliminates the need for an external translator, which saves both space and BOM cost. For more information on 1.8 V logic implementations refer to Simplifying Design with 1.8 V logic Muxes and Switches

8.3.4 Fail-Safe Logic

The TMUX1247 supports Fail-Safe Logic on the control input pin (SEL) allowing for operation up to 5.5 V, regardless of the state of the supply pin. This feature allows voltages on the control pin to be applied before the supply pin, protecting the device from potential damage. Fail-Safe Logic minimizes system complexity by removing the need for power supply sequencing on the logic control pins. For example, the Fail-Safe Logic feature allows the select pin of the TMUX1247 to be ramped to 5.5 V while $V_{DD} = 0$ V. Additionally, the feature enables operation of the TMUX1247 with $V_{DD} = 1.2$ V while allowing the select pin to interface with a logic level of another device up to 5.5 V.



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8.4 Device Functional Modes

The select (SEL) pin of the TMUX1247 controls which switch is connected to the drain of the device. When a given input is not selected, that source pin is in high impedance mode (HI-Z). The control pins can be as high as 5.5 V.

The TMUX1247 can be operated without any external components except for the supply decoupling capacitors. Unused logic control pins should be tied to GND or V_{DD} in order to ensure the device does not consume additional current as highlighted in *Implications of Slow or Floating CMOS Inputs*. Unused signal path inputs (Sx or D) should be connected to GND.

8.5 Truth Tables

表 1. TMUX1247 Truth Table

CONTROL LOGIC (SEL)	Selected Source (Sx) Connected To Drain (D) Pin
0	S1
1	S2

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9 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

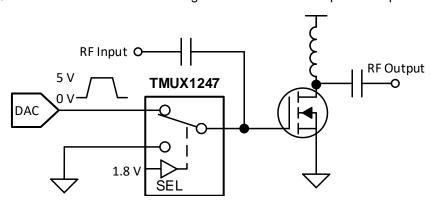
9.1 Application Information

The TMUX12xx family offers good system performance across a wide operating supply (1.08V to 5.5V). These devices include 1.8V logic compatible control input pins that enable operation in systems with 1.8V I/O rails. Additionally, the control input pin supports Fail-Safe Logic which allows for operation up to 5.5V, regardless of the state of the supply pin. This protection stops the logic pins from back-powering the supply rail. These features of the TMUX12xx, a family of general purpose multiplexers and switches, reduce system complexity, board size, and overall system cost.

9.2 Typical Application

9.2.1 Input Control for Power Amplifier

One application of the TMUX1247 is for input control of a power amplifier. Utilizing a switch allows a system to control when the DAC is connected to the power amplifier, and can stop biasing the power amplifier by switching the gate to GND. 2 17 shows the TMUX1247 configured for control of the power amplifier.



☑ 17. Input Control of Power Amplifier



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Typical Application (continued)

9.2.1.1 Design Requirements

This design example uses the parameters listed in 表 3.

表 2. Design Parameters

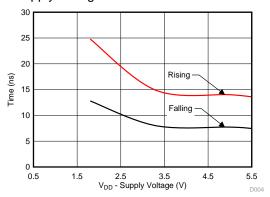
PARAMETERS	VALUES		
Supply (V _{DD})	5 V		
Mux I/O signal range	0 V to V _{DD} (Rail to Rail)		
Control logic thresholds	1.8 V compatible (up to 5.5V)		

9.2.1.2 Detailed Design Procedure

The application shown in 🗵 17 demonstrates how to toggle between the DAC output and GND for control of a power amplifier using a single control input. The DAC output is utilized to bias the gate of the power amplifier and can be disconnected from the circuit using the select pin of the switch. The TMUX1247 can support 1.8-V logic signals on the control input, allowing the device to interface with low logic controls of an FPGA or MCU. The TMUX1247 can be operated without any external components except for the supply decoupling capacitors. The select pin is recommended to have a weak pull-down or pull-up resistor to ensure the input is in a known state. All inputs to the switch must fall within the recommend operating conditions of the TMUX1247 including signal range and continuous current. For this design with a supply of 5 V the signal range can be 0 V to 5 V and the max continuous current can be 30 mA.

9.2.1.3 Application Curve

A key parameter for this application is the transition time of the device. Faster transition time allows the system to toggle between input sources at a faster rate and allows the output to settle to the final value. The TMUX1247 has a transition time that varies with supply voltage and is shown in 218



 $T_A = 25^{\circ}C$

図 18. T_{transition} vs Supply Voltage

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9.2.2 Switchable Operational Amplifier Gain Setting

Another example application of the TMUX1247 is to change an Op Amp from unity gain setting to an inverting amplifier configuration. Utilizing a switch allows a system to have a configurable gain and allows the same architecture to be utilized across the board for various inputs to the system. ☒ 19 shows the TMUX1247 configured for gain setting application.

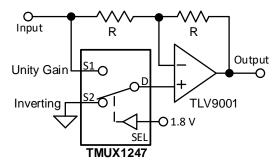


図 19. Switchable Op Amp Gain Setting

9.2.2.1 Design Requirements

This design example uses the parameters listed in 表 3.

表 3. Design Parameters

PARAMETERS	VALUES
Input Signal	0 V to 2.75 V
Mux Supply (V _{DD})	2.75 V
Op Amp Supply (V ₊ / V ₋)	±2.75 V
Mux I/O signal range	0 V to V _{DD} (Rail to Rail)
Control logic thresholds	1.8 V compatible (up to 5.5V)



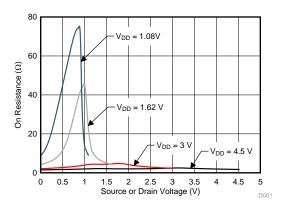
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9.2.2.2 Detailed Design Procedure

The application shown in 2 19 demonstrates how to use a single control input and toggle between gain settings of -1 and +1. If switching between inverting and unity gain is not required, the TMUX1247 can be utilized in the feedback path to select different feedback resistors and provide scalable gain settings for configurable signal conditioning.

The TMUX1247 can be operated without any external components except for the supply decoupling capacitors. The select pin is recommended to have a weak pull-down or pull-up resistor to ensure the input is in a known state. All inputs to the switch must fall within the recommend operating conditions of the TMUX1247 including signal range and continuous current. For this design with a supply of 2.75 V the signal range can be 0 V to 2.75 V and the max continuous current can be 30 mA.

9.2.2.3 Application Curve



 $T_A = 25^{\circ}C$

図 20. On-Resistance vs Source or Drain Voltage

10 Power Supply Recommendations

The TMUX1247 operates across a wide supply range of 1.08 V to 5.5 V. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices.

Power-supply bypassing improves noise margin and prevents switching noise propagation from the V_{DD} supply to other components. Good power-supply decoupling is important to achieve optimum performance. For improved supply noise immunity, use a supply decoupling capacitor ranging from 0.1 μ F to 10 μ F from V_{DD} to ground. Place the bypass capacitors as close to the power supply pins of the device as possible using low-impedance connections. TI recommends using multi-layer ceramic chip capacitors (MLCCs) that offer low equivalent series resistance (ESR) and inductance (ESL) characteristics for power-supply decoupling purposes. For very sensitive systems, or for systems in harsh noise environments, avoiding the use of vias for connecting the capacitors to the device pins may offer superior noise immunity. The use of multiple vias in parallel lowers the overall inductance and is beneficial for connections to ground planes.

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11 Layout

11.1 Layout Guidelines

11.1.1 Layout Information

When a PCB trace turns a corner at a 90° angle, a reflection can occur. A reflection occurs primarily because of the change of width of the trace. At the apex of the turn, the trace width increases to 1.414 times the width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self–inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. Z 21 shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.

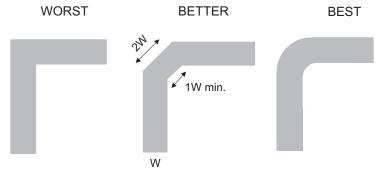


図 21. Trace Example

Route high-speed signals using a minimum of vias and corners which reduces signal reflections and impedance changes. When a via must be used, increase the clearance size around it to minimize its capacitance. Each via introduces discontinuities in the signal's transmission line and increases the chance of picking up interference from the other layers of the board. Be careful when designing test points, throughhole pins are not recommended at high frequencies.

- Decouple the V_{DD} pin with a 0.1-µF capacitor, placed as close to the pin as possible. Make sure that the
 capacitor voltage rating is sufficient for the V_{DD} supply.
- Keep the input lines as short as possible.
- Use a solid ground plane to help reduce electromagnetic interference (EMI) noise pickup.
- Do not run sensitive analog traces in parallel with digital traces. Avoid crossing digital and analog traces if possible, and only make perpendicular crossings when necessary.

11.2 Layout Example

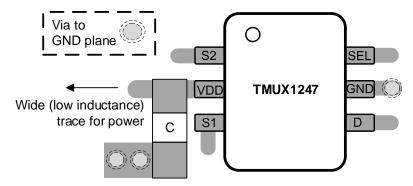


図 22. TMUX1247 Layout Example



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12 デバイスおよびドキュメントのサポート

12.1 ドキュメントのサポート

12.1.1 関連資料

テキサス・インスツルメンツ、『低CONマルチプレクサにおける安定性の問題の改善』 テキサス・インスツルメンツ、『1.8Vロジックのマルチプレクサおよびスイッチにおける設計の単純化』 テキサス・インスツルメンツ、『電源オフ保護を備えた信号スイッチで電源シーケンスを不要に』 テキサス・インスツルメンツ、『高電圧アナログ・マルチプレクサのシステムレベル保護』

12.2 ドキュメントの更新通知を受け取る方法

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12.3 コミュニティ・リソース

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12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 メカニカル、パッケージ、および注文情報

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PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
TMUX1247DCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	247	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

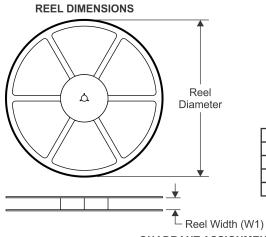
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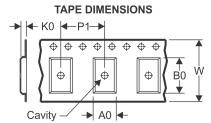
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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TMUX1247DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

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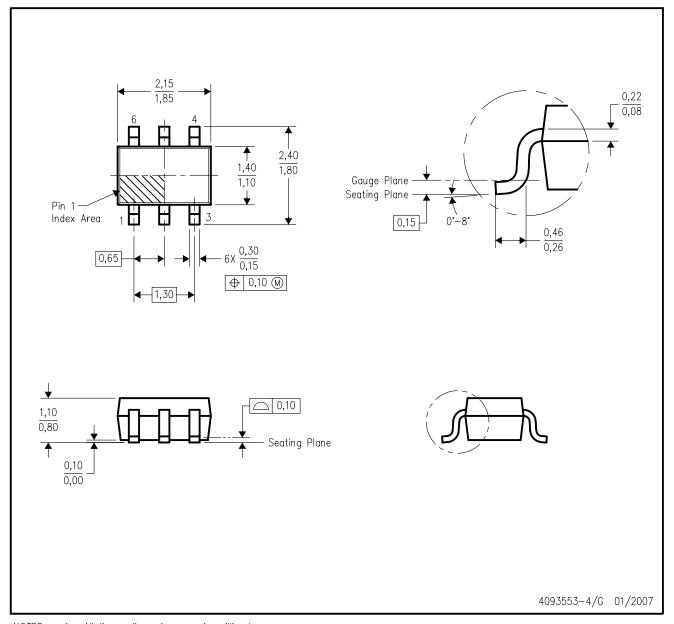


*All dimensions are nominal

I	Device Package Type		Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	TMUX1247DCKR	SC70	DCK	6	3000	180.0	180.0	18.0	

DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



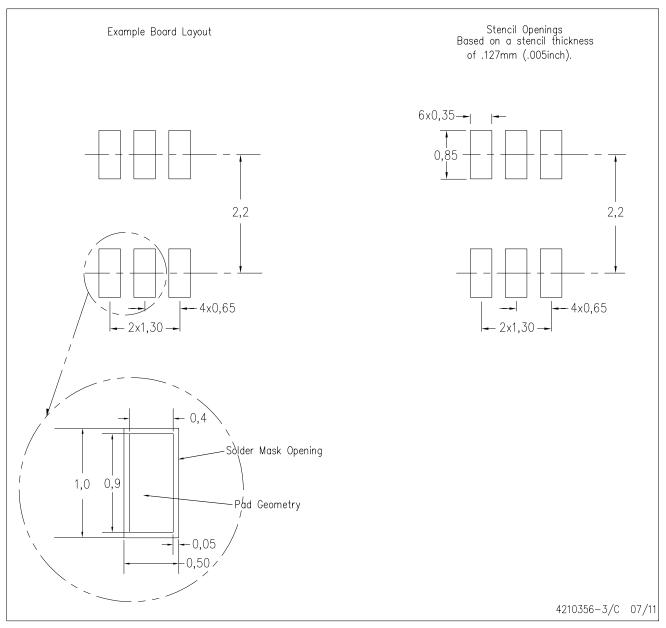
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AB.



DCK (R-PDSO-G6)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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